Exam 12.12.2013

S-104.3610 Nanotechnology (5 cr)

Please answer either in English or Finnish.

- 1. Explain briefly (max. 2 pages altogether, draw schematics if needed):
 - a) EUV lithography
 - b) dip-pen nanolithography
 - c) role of thiols in molecular electronics
 - d) photoluminescence
 - e) Q-factor of a resonator
 - f) electrophoresis(each 1 p)
- 2. a) Resolution enhancement techniques in optical lithography (3 p)
 - b) Operation of piezoelectric scanners in SPM (3 p)
- a) Compare so called "top-down" and "bottom-up" methodologies. What are the advantages and difficulties in each approach? (3 p)
 - b) Three examples of biomimetics (3 p)
- 4. Properties, fabrication and applications of graphene (6 p)
- 5. a) Explain how to estimate the weight of a single molecule (3 p)
 - b) Explain how to achieve superhydrophobic surface using surface structure, contact angle and interfacial energy (3 p)